

FEATURES

Operates from 1.65 V to 3.6 V supply rails
 Bidirectional level translation, unidirectional signal path
 8-lead SOT-23 and MSOP packages
 Bypass or normal operation
 Short circuit protection

APPLICATIONS

JTAG chain bypassing
 Daisy-chain bypassing
 Digital switching

FUNCTIONAL BLOCK DIAGRAM

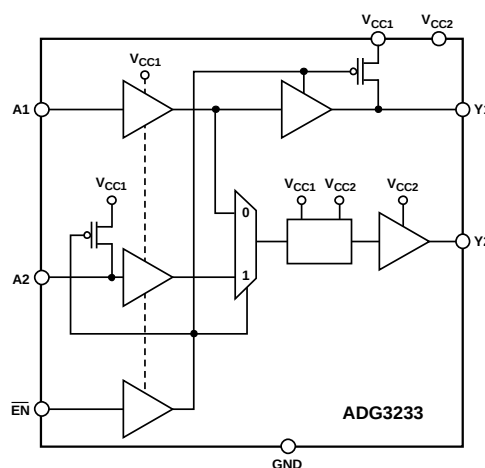


Figure 1.

GENERAL DESCRIPTION

The ADG3233¹ is a bypass switch designed on a submicron process that operates from supplies as low as 1.65 V. The device is guaranteed for operation over the supply range 1.65 V to 3.6 V. It operates from two supply voltages, allowing bidirectional level translation, that is, it translates low voltages to higher voltages and vice versa. The signal path is unidirectional, meaning data may only flow from A → Y.

This type of device may be used in applications that require a bypassing function. It is ideally suited to bypassing devices in a JTAG chain or in a daisy-chain loop. One switch could be used for each device or a number of devices, thus allowing easy bypassing of one or more devices in a chain. This may be particularly useful in reducing the time overhead in testing devices in the JTAG chain or in daisy-chain applications where the user does not wish to change the settings of a particular device.

The bypass switch is packaged in two of the smallest footprints available for its required pin count. The 8-lead SOT-23 package requires only 2.9 mm × 2.8 mm board space, while the MSOP package occupies approximately 3 mm × 4.9 mm board area.

PRODUCT HIGHLIGHTS

1. Bidirectional level translation matches any voltage level from 1.65 V to 3.6 V.
2. The bypass switch offers high performance and is fully guaranteed across the supply range.
3. Short circuit protection.
4. Tiny 8-lead SOT-23 package and 8-lead MSOP.

Table 1. Truth Table

EN	Signal Path	Function
L	A1 → Y2, Y1 → V _{CC1}	Enable bypass mode
H	A1 → Y1, A2 → Y2	Enable normal mode

¹ U.S. Patent Number: 7,369,385 B2.

ADG3233* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- Evaluation Board for 8 lead MSOP Devices in the Switch/Mux Portfolio

DOCUMENTATION

Application Notes

- AN-349: Keys to Longer Life for CMOS

Data Sheet

- ADG3233: Low Voltage 1.65 V to 3.6 V, (Up/Down) Logic Level Translation, Bypass Switch Data Sheet

User Guides

- UG-893: Evaluating the 8-Lead MSOP Devices in the Switch/Mux Portfolio

TOOLS AND SIMULATIONS

- ADG3233 IBIS Model

REFERENCE MATERIALS

Product Selection Guide

- Switches and Multiplexers Product Selection Guide

Technical Articles

- CMOS Switches Offer High Performance in Low Power, Wideband Applications
- Data-acquisition system uses fault protection
- Enhanced Multiplexing for MEMS Optical Cross Connects

DESIGN RESOURCES

- ADG3233 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all ADG3233 EngineerZone Discussions.

SAMPLE AND BUY

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TECHNICAL SUPPORT

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DOCUMENT FEEDBACK

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REVISION HISTORY

4/15—Rev. B to Rev. C

Changes to Table 4.....	7
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7/13—Rev. A to Rev. B

Changes to Table 1	1
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7/11—Rev. 0 to Rev. A

Changes to Patent Number, General Description Section, and Product Highlights Section	1
Changes to $V_{CC} = V_{CC1} = V_{CC2} = 2.5 \text{ V} \pm 0.2 \text{ V}$, ENABLE Time $\overline{\text{EN}} \rightarrow \text{Y1}$, Table 2	4
Changes to Table 3.....	6
Updated Outline Dimensions	15
Changes to Ordering Guide	16

5/03—Revision 0: Initial Version

SPECIFICATIONS

$V_{CC1} = V_{CC2} = 1.65\text{ V to }3.6\text{ V}$, $GND = 0\text{ V}$, all specifications T_{MIN} to T_{MAX} , unless otherwise noted.

Table 2.

Parameter ¹	Symbol	Test Conditions/Comments	Min	Typ ²	Max	Unit		
LOGIC INPUTS/OUTPUTS ³								
Input High Voltage ⁴	V _{IH}	V _{CC2} = 1.65 V to 3.6 V, GND = 0 V	1.35			V		
		V _{CC1} = 3.0 V to 3.6 V	1.35		V			
		V _{CC1} = 2.3 V to 2.7 V	0.65 × V _{CC}		V			
Input Low Voltage ⁴	V _{IL}	V _{CC1} = 1.65 V to 1.95 V				V		
		V _{CC1} = 3.0 V to 3.6 V			0.8	V		
		V _{CC1} = 2.3 V to 2.7 V			0.7	V		
Output High Voltage (Y1)	V _{OH}	V _{CC1} = 1.65 V to 1.95 V			0.35 × V _{CC}	V		
		I _{OH} = −100 μA, V _{CC1} = 3.0 V to 3.6 V	2.4			V		
		I _{OH} = −100 μA, V _{CC1} = 2.3 V to 2.7 V	2.0			V		
		I _{OH} = −100 μA, V _{CC1} = 1.65 V to 1.95 V	V _{CC} − 0.45			V		
		I _{OH} = −4 mA, V _{CC1} = 2.3 V to 2.7 V	2.0			V		
		I _{OH} = −4 mA, V _{CC1} = 1.65 V to 1.95 V	V _{CC} − 0.45			V		
Output Low Voltage (Y1)	V _{OL}	I _{OH} = −8 mA, V _{CC1} = 3.0 V to 3.6 V	2.4			V		
		I _{OL} = 100 μA, V _{CC1} = 3.0 V to 3.6 V			0.40	V		
		I _{OL} = 100 μA, V _{CC1} = 2.3 V to 2.7 V			0.40	V		
		I _{OL} = 100 μA, V _{CC1} = 1.65 V to 1.95 V			0.45	V		
		I _{OL} = 4 mA, V _{CC1} = 2.3 V to 2.7 V			0.40	V		
		I _{OL} = 4 mA, V _{CC1} = 1.65 V to 1.95 V			0.45	V		
		I _{OL} = 8 mA, V _{CC1} = 3.0 V to 3.6 V			0.40	V		
		LOGIC OUTPUTS ³						
		Output High Voltage (Y2)	V _{OH}	V _{CC1} = 1.65 V to 3.6 V, GND = 0 V	2.4			V
I _{OH} = −100 μA, V _{CC2} = 3.0 V to 3.6 V	2.0				V			
I _{OH} = −100 μA, V _{CC2} = 2.3 V to 2.7 V	V _{CC} − 0.45				V			
I _{OH} = −4 mA, V _{CC2} = 2.3 V to 2.7 V	2.0				V			
I _{OH} = −4 mA, V _{CC2} = 1.65 V to 1.95 V	V _{CC} − 0.45				V			
I _{OH} = −8 mA, V _{CC2} = 3.0 V to 3.6 V	2.4				V			
Output Low Voltage (Y2)	V _{OL}	I _{OH} = −8 mA, V _{CC2} = 3.0 V to 3.6 V			0.40	V		
		I _{OL} = 100 μA, V _{CC2} = 3.0 V to 3.6 V			0.40	V		
		I _{OL} = 100 μA, V _{CC2} = 2.3 V to 2.7 V			0.45	V		
		I _{OL} = 100 μA, V _{CC2} = 1.65 V to 1.95 V			0.40	V		
		I _{OL} = 4 mA, V _{CC2} = 2.3 V to 2.7 V			0.45	V		
		I _{OL} = 4 mA, V _{CC2} = 1.65 V to 1.95 V			0.40	V		
		I _{OL} = 8 mA, V _{CC2} = 3.0 V to 3.6 V			0.40	V		
SWITCHING CHARACTERISTICS ^{4, 5}								
V _{CC} = V _{CC1} = V _{CC2} = 3.3 V ± 0.3 V								
Propagation Delay, t _{PD}								
A1 → Y1 Normal Mode	t _{PHL} , t _{PLH}	C _L = 30 pF, V _I = V _{CC} /2		3.5	5.4	ns		
A2 → Y2 Normal Mode	t _{PHL} , t _{PLH}	C _L = 30 pF, V _I = V _{CC} /2		3.5	5.4	ns		
A1 → Y2 Bypass Mode	t _{PHL} , t _{PLH}	C _L = 30 pF, V _I = V _{CC} /2		4	6.5	ns		
ENABLE Time $\overline{\text{EN}}$ → Y1	t _{EN} $\overline{}$	C _L = 30 pF, V _I = V _{CC} /2		4	6	ns		
DISABLE Time $\overline{\text{EN}}$ → Y1	t _{DIS}	C _L = 30 pF, V _I = V _{CC} /2		2.8	4	ns		
ENABLE Time $\overline{\text{EN}}$ → Y2	t _{EN} $\overline{}$	C _L = 30 pF, V _I = V _{CC} /2		4.5	6.5	ns		
DISABLE Time $\overline{\text{EN}}$ → Y2	t _{DIS}	C _L = 30 pF, V _I = V _{CC} /2		4	6.5	ns		

Parameter ¹	Symbol	Test Conditions/Comments	Min	Typ ²	Max	Unit
$V_{CC} = V_{CC1} = V_{CC2} = 2.5\text{ V} \pm 0.2\text{ V}$						
Propagation Delay, t_{PD}						
A1 $\rightarrow$ Y1 Normal Mode	t_{PHL}, t_{PLH}	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		4.5	6.2	ns
A2 $\rightarrow$ Y2 Normal Mode	t_{PHL}, t_{PLH}	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		4.5	6.2	ns
A1 $\rightarrow$ Y2 Bypass Mode	t_{PHL}, t_{PLH}	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		4.5	6.5	ns
ENABLE Time $\overline{EN} \rightarrow Y1$	t_{EN}^-	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		5	7.2	ns
DISABLE Time $\overline{EN} \rightarrow Y1$	t_{DIS}	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		3.2	4.7	ns
ENABLE Time $\overline{EN} \rightarrow Y2$	t_{EN}^-	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		5	7.7	ns
DISABLE Time $\overline{EN} \rightarrow Y2$	t_{DIS}	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		4.8	7.2	ns
$V_{CC} = V_{CC1} = V_{CC2} = 1.8\text{ V} \pm 0.15\text{ V}$						
Propagation Delay, t_{PD}						
A1 $\rightarrow$ Y1 Normal Mode	t_{PHL}, t_{PLH}	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		6.7	10	ns
A2 $\rightarrow$ Y2 Normal Mode	t_{PHL}, t_{PLH}	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		6.5	10	ns
A1 $\rightarrow$ Y2 Bypass Mode	t_{PHL}, t_{PLH}	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		6.5	10.25	ns
ENABLE Time $\overline{EN} \rightarrow Y1$	t_{EN}^-	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		7	10.5	ns
DISABLE Time $\overline{EN} \rightarrow Y1$	t_{DIS}	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		4.4	6.5	ns
ENABLE Time $\overline{EN} \rightarrow Y2$	t_{EN}^-	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		7	12	ns
DISABLE Time $\overline{EN} \rightarrow Y2$	t_{DIS}	$C_L = 30\text{ pF}, V_T = V_{CC}/2$		6.5	10.5	ns
Input Leakage Current	I_I	$0 \leq V_{IN} \leq 3.6\text{ V}$			± 1	μA
Output Leakage Current	I_O	$0 \leq V_{IN} \leq 3.6\text{ V}$			± 1	μA
POWER REQUIREMENTS						
Power Supply Voltages	V_{CC1}		1.65		3.6	V
	V_{CC2}		1.65		3.6	V
Quiescent Power Supply Current	I_{CC1}	Digital inputs = 0 V or V_{CC}			2	μA
	I_{CC2}	Digital inputs = 0 V or V_{CC}			2	μA
Increase in I_{CC} per Input	ΔI_{CC1}	$V_{CC} = 3.6\text{ V}$, one input at 3.0 V; others at V_{CC} or GND			0.75	μA

¹ Temperature range is as follows: B Version: -40°C to $+85^\circ\text{C}$.

² All typical values are at $V_{CC} = V_{CC1} = V_{CC2}$, $T_A = 25^\circ\text{C}$, unless otherwise stated.

³ V_{IL} and V_{IH} levels are specified with respect to V_{CC1} , V_{OH} , and V_{OL} levels for Y1 are specified with respect to V_{CC1} , and V_{OH} , and V_{OL} levels are specified for Y2 with respect to V_{CC2} .

⁴ Guaranteed by design, not subject to production test.

⁵ See the Test Waveforms section.

TEST WAVEFORMS

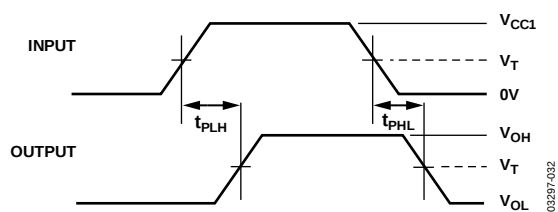


Figure 2. Propagation Delay

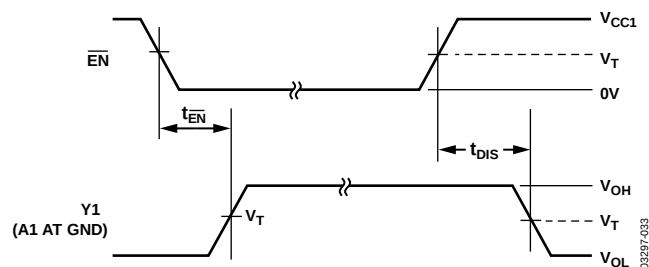


Figure 3. Y1 Enable and Disable Times

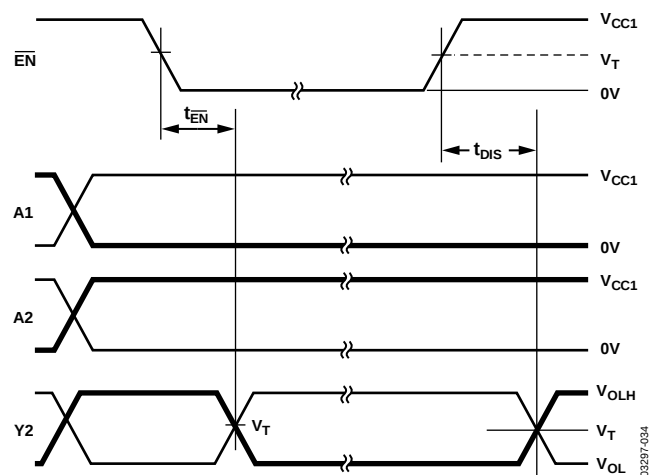


Figure 4. Y2 Enable and Disable Times

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 3.

Parameter	Rating
V_{CC} to GND	$-0.3\text{ V to }+4.6\text{ V}$
Digital Inputs to GND	$-0.3\text{ V to }+4.6\text{ V}$
A1, $\overline{\text{EN}}$	$-0.3\text{ V to }+4.6\text{ V}$
A2	$-0.3\text{ V to }V_{CC1} + 0.3\text{ V}$
DC Output Current	25 mA
Operating Temperature Range	
Industrial (B Version)	$-40^\circ\text{C to }+85^\circ\text{C}$
Storage Temperature Range	$-65^\circ\text{C to }+150^\circ\text{C}$
Junction Temperature	150°C
8-Lead MSOP	
θ_{JA} Thermal Impedance	206°C/W
θ_{JC} Thermal Impedance	43°C/W
8-Lead SOT-23	
θ_{JA} Thermal Impedance	211°C/W
Lead Temperature, Soldering (10 sec)	300°C
IR Reflow, Peak Temperature (<20 sec)	235°C
Soldering (Pb-Free)	
Reflow, Peak Temperature	$260(+0/-5)^\circ\text{C}$
Time at Peak Temperature	20 sec to 40 sec

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Only one absolute maximum rating may be applied at any one time.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

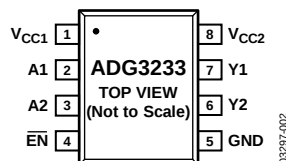


Figure 5. 8-Lead SOT-23 Package (RJ-8)

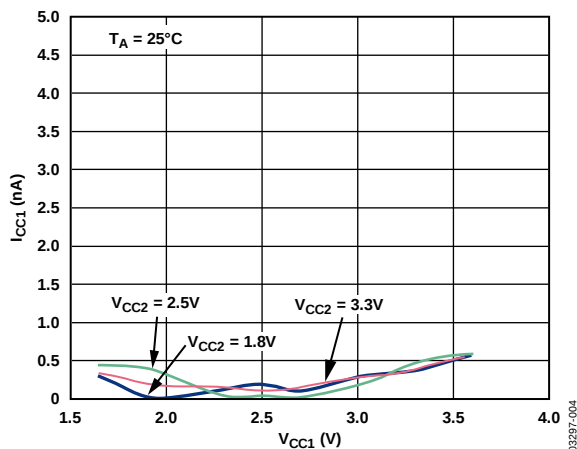
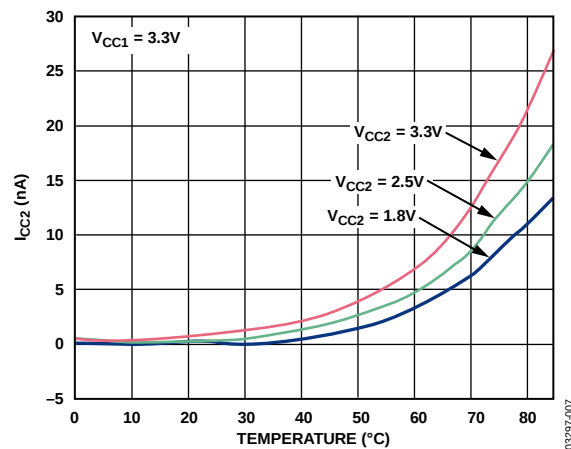
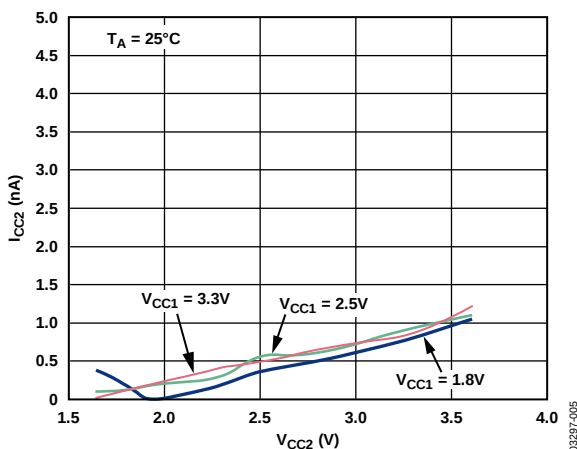
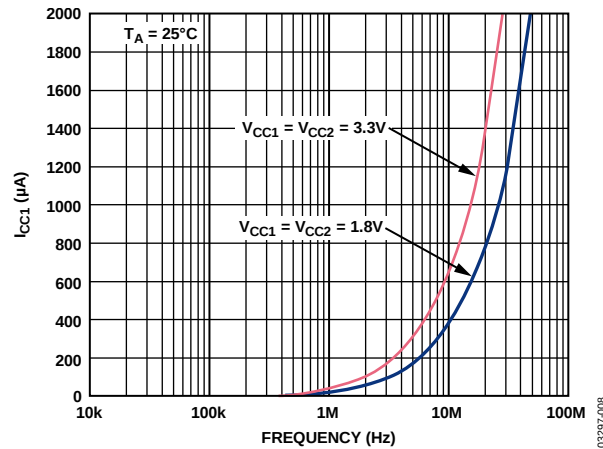
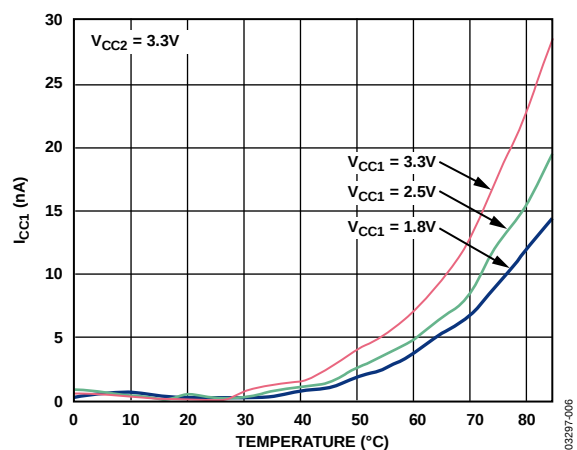
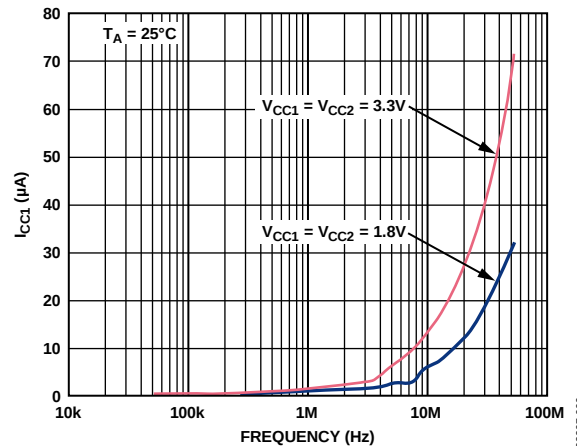


Figure 6. 8-Lead MSOP Package (RM-8)

Table 4. Pin Function Descriptions

Pin No.		Mnemonic	Description
RJ-8	RM-8		
1	8	V _{CC1}	Supply Voltage 1, can be any supply voltage from 1.65 V to 3.6 V.
8	1	V _{CC2}	Supply Voltage 2, can be any supply voltage from 1.65 V to 3.6 V.
2	7	A1	Input Referred to V _{CC1} .
3	6	A2	Input Referred to V _{CC1} .
7	2	Y1	Output Referred to V _{CC1} .
6	3	Y2	Output Referred to V _{CC2} . Voltage levels appearing at Y2 will be translated from a V _{CC1} voltage level to a V _{CC2} voltage level.
4	5	$\overline{\text{EN}}$	Active Low Device Enable. When low, bypass mode is enabled; when high, the device is in normal mode.
5	4	GND	Device Ground.

TYPICAL PERFORMANCE CHARACTERISTICS

Figure 7. I_{CC1} vs. V_{CC1} Figure 10. I_{CC2} vs. TemperatureFigure 8. I_{CC2} vs. V_{CC2} Figure 11. I_{CC1} vs. Frequency, Normal ModeFigure 9. I_{CC1} vs. TemperatureFigure 12. I_{CC1} vs. Frequency, Bypass Mode

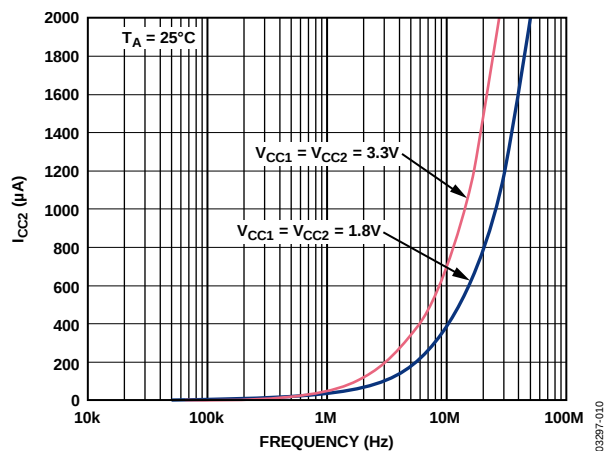
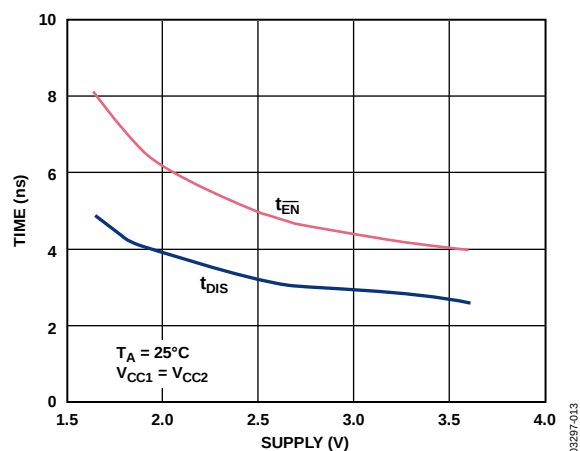
Figure 13. I_{CC2} vs. Frequency, Normal Mode

Figure 16. Y2 Enable, Disable Time vs. Supply

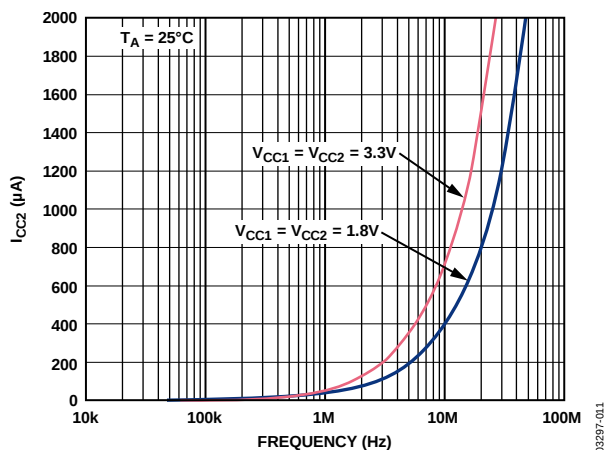
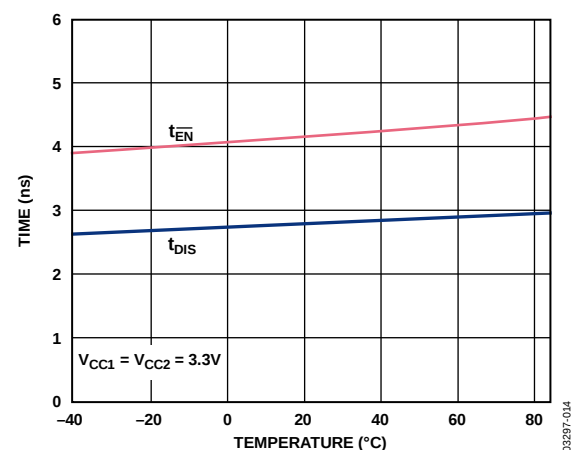
Figure 14. I_{CC2} vs. Frequency, Bypass Mode

Figure 17. Y1 Enable, Disable Time vs. Temperature

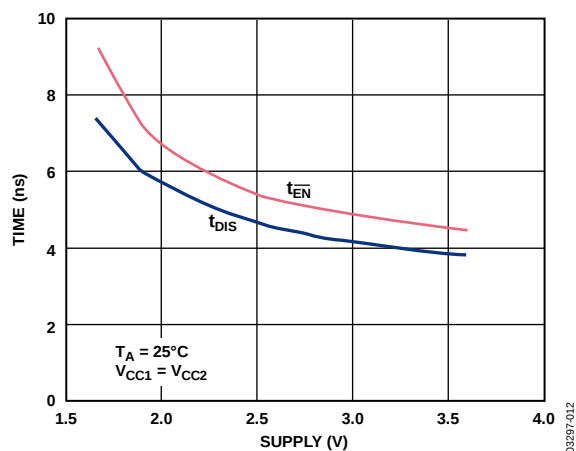


Figure 15. Y1 Enable, Disable Time vs. Supply

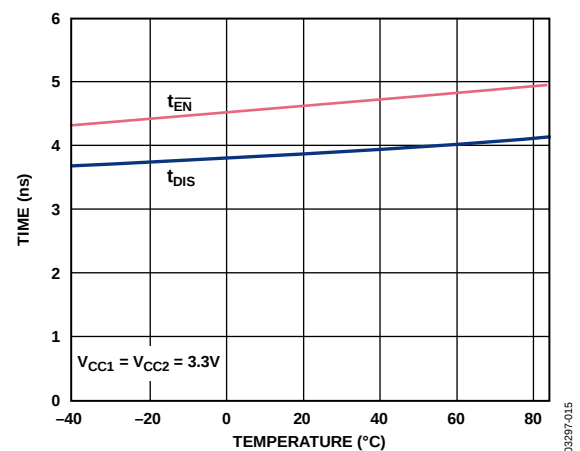


Figure 18. Y2 Enable, Disable Time vs. Temperature

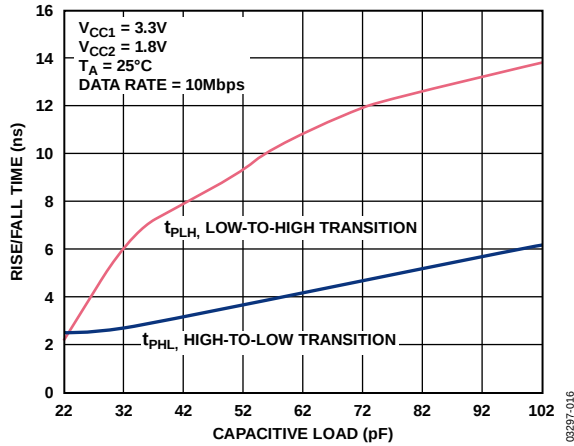


Figure 19. Rise/Fall Time vs. Capacitive Load, A1 → Y1, A2 → Y2

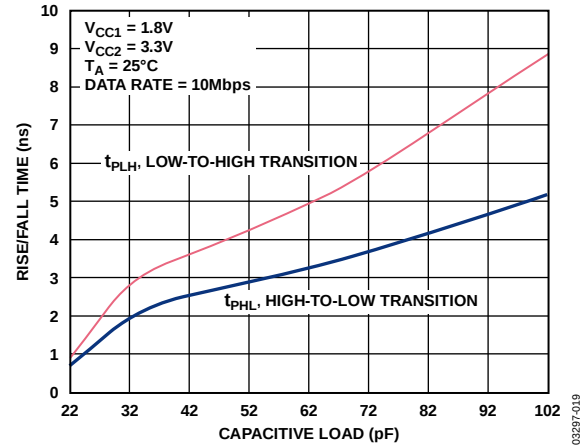


Figure 22. Rise/Fall Time vs. Capacitive Load, A1 → Y2, Bypass Mode

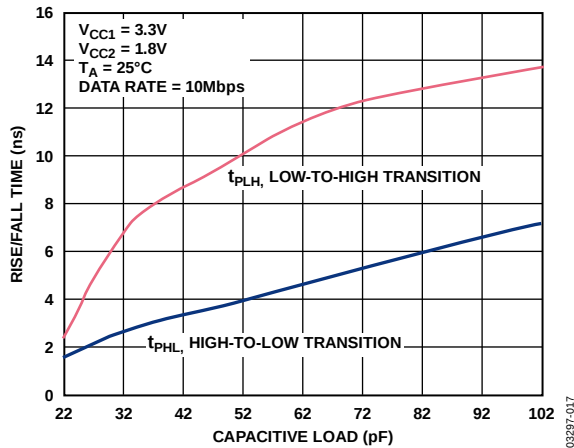


Figure 20. Rise/Fall Time vs. Capacitive Load, A1 → Y2, Bypass Mode

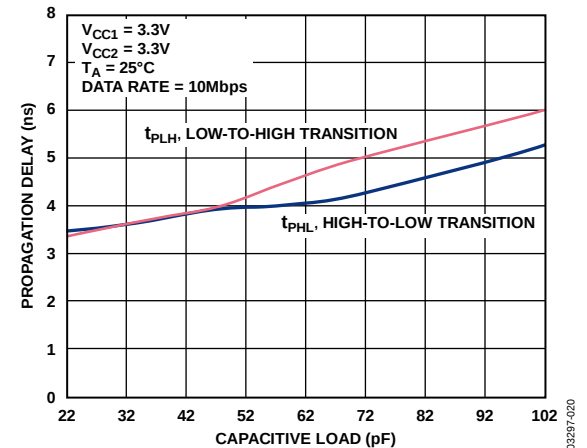


Figure 23. Propagation Delay vs. Capacitive Load A1 → Y1

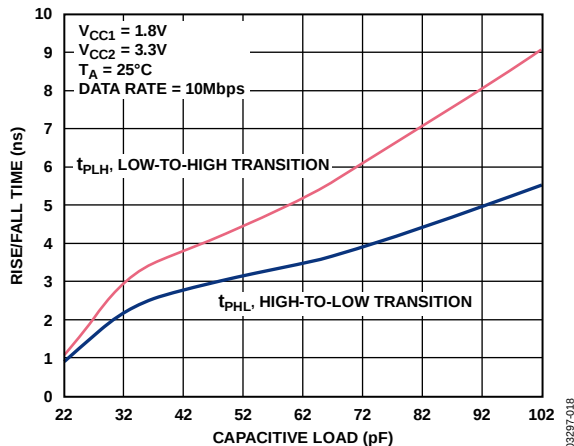


Figure 21. Rise/Fall Time vs. Capacitive Load, A1 → Y1, A2 → Y2

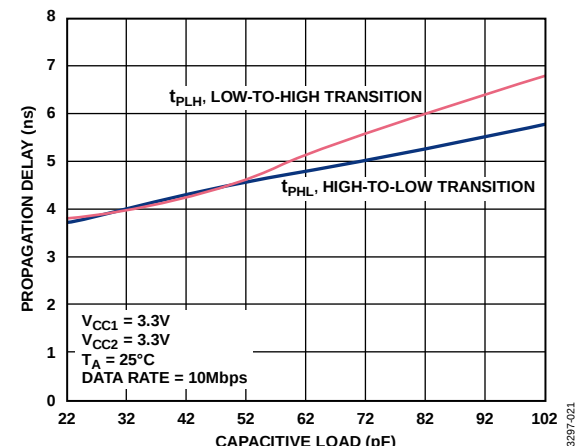


Figure 24. Propagation Delay vs. Capacitive Load A2 → Y2

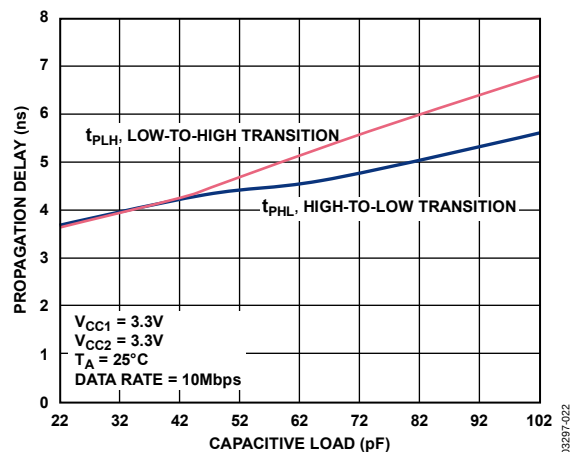


Figure 25. Propagation Delay vs. Capacitive Load A1 → Y2, Bypass Mode

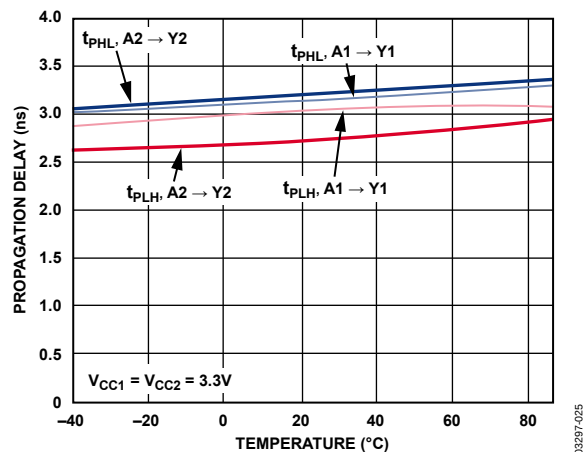


Figure 28. Propagation Delay vs. Temperature, Normal Mode

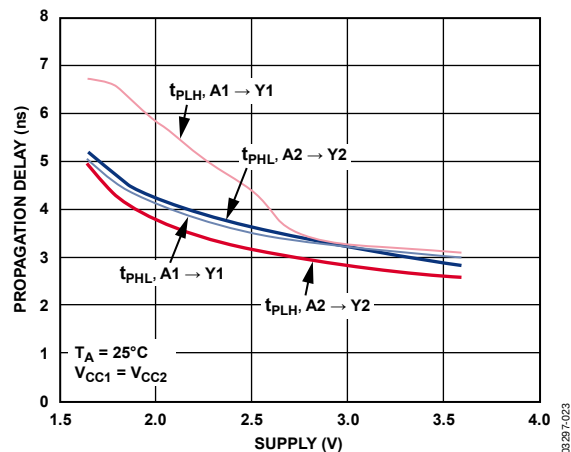


Figure 26. Propagation Delay vs. Supply, Normal Mode

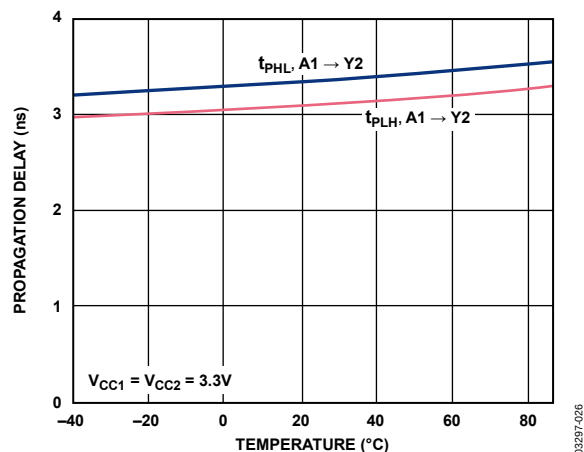


Figure 29. Propagation Delay vs. Temperature, Bypass Mode

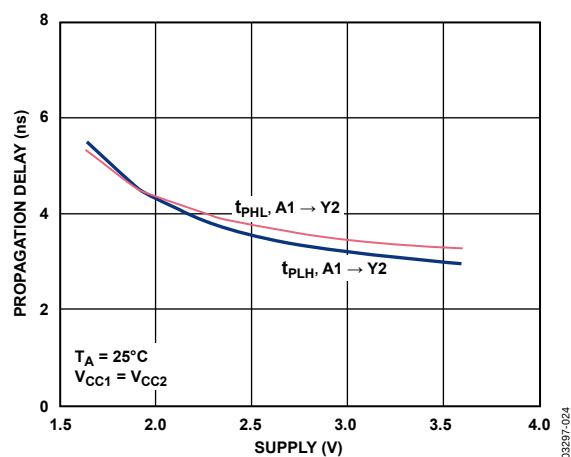
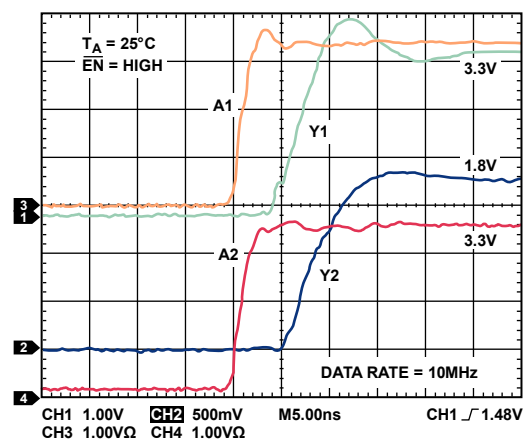


Figure 27. Propagation Delay vs. Supply, Bypass Mode

Figure 30. Normal Mode $V_{CC1} = 3.3\text{ V}$, $V_{CC2} = 1.8\text{ V}$

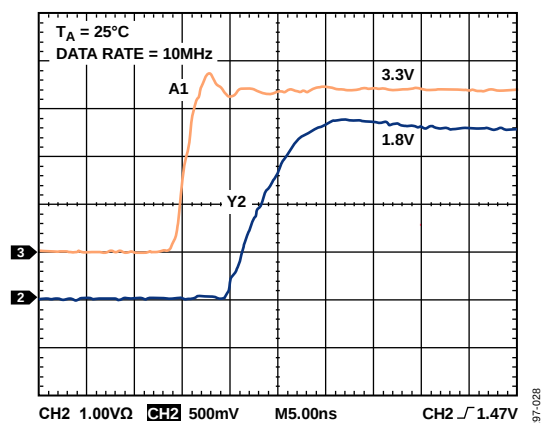
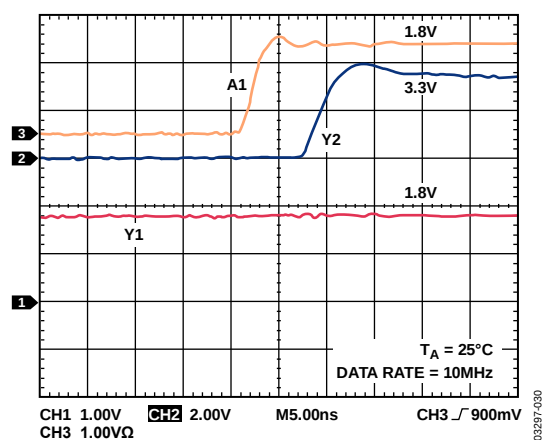
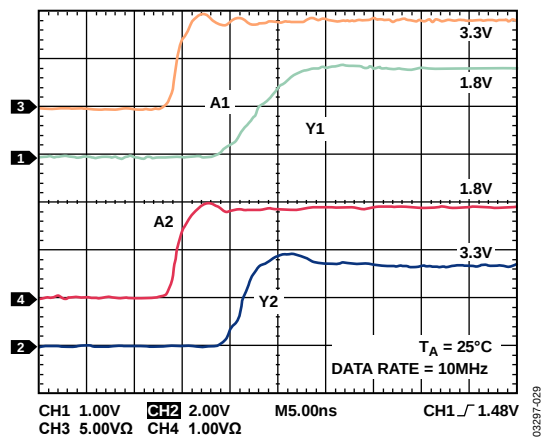
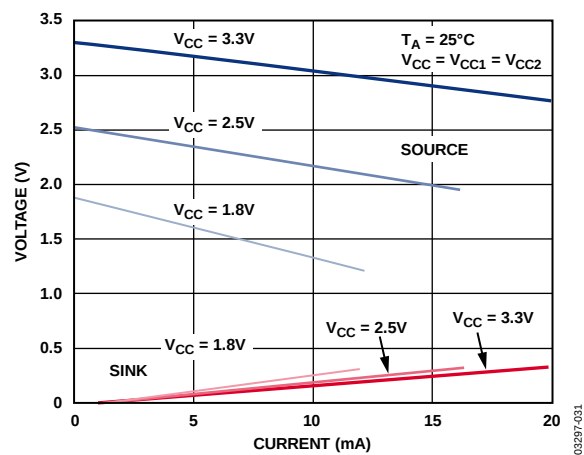
Figure 31. Bypass Mode, $V_{CC1} = 3.3V$, $V_{CC2} = 1.8V$ Figure 33. Bypass Mode, $V_{CC1} = 1.8V$, $V_{CC2} = 3.3V$ Figure 32. Normal Mode, $V_{CC1} = 1.8V$, $V_{CC2} = 3.3V$ 

Figure 34. Y1 and Y2 Source and Sink Current

THEORY OF OPERATION

The ADG3233 is a bypass switch designed on a submicron process that operates from supplies as low as 1.65 V. The device is guaranteed for operation over the supply range 1.65 V to 3.6 V. It operates from two supply voltages, allowing bidirectional level translation, that is, it translates low voltages to higher voltages and vice versa. The signal path is unidirectional, meaning data may only flow from A → Y.

A1 AND $\overline{\text{EN}}$ INPUT

The A1 and enable ($\overline{\text{EN}}$) inputs have V_{IL}/V_{IH} logic levels so that the part can accept logic levels of V_{OL}/V_{OH} from Device 0 or the controlling device independent of the value of the supply being used by the controlling device. These inputs (A1, $\overline{\text{EN}}$) are capable of accepting inputs outside the V_{CC1} supply range. For example, the V_{CC1} supply applied to the bypass switch could be 1.8 V while Device 0 could be operating from a 2.5 V or 3.3 V supply rail, there are no internal diodes to the supply rails, so the device can handle inputs above the supply but inside the absolute maximum ratings.

NORMAL OPERATION

Figure 35 shows the bypass switch being used in normal mode. In this mode, the signal paths are from A1 → Y1 and A2 → Y2. The device will level translate the signal applied to A1 to a V_{CC1} logic level (this level translation can be either to a higher or lower supply) and route the signal to the Y1 output, which will have standard V_{OL}/V_{OH} levels for V_{CC1} supplies. The signal is then passed through Device 1 and back to the A2 input pin of the bypass switch.

The logic level inputs of A2 are with respect to the V_{CC1} supply. The signal will be level translated from V_{CC1} to V_{CC2} and routed to the Y2 output pin of the bypass switch. Y2 output logic levels are with respect to the V_{CC2} supply.

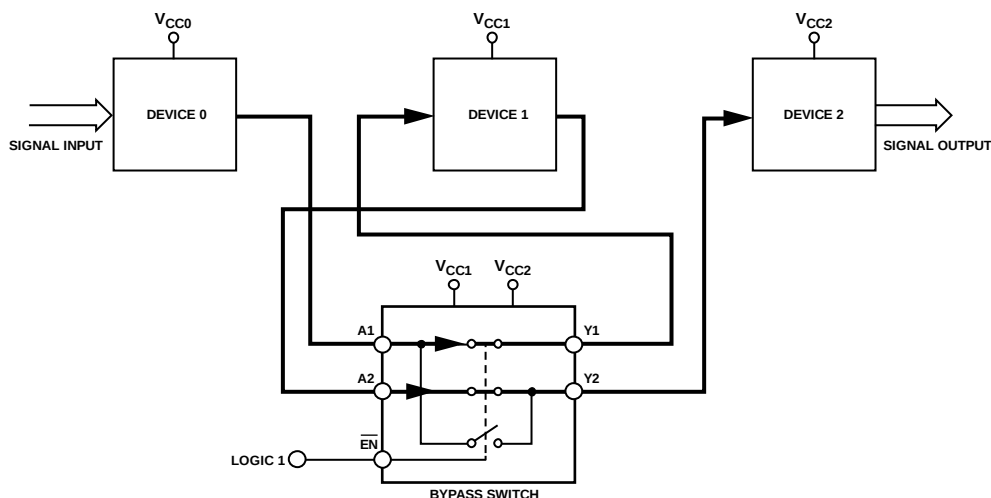


Figure 35. Bypass Switch in Normal Mode

03297-035

BYPASS OPERATION

Figure 36 illustrates the device as used in bypass mode. The signal path is now from A1 directly to Y2, thus bypassing Device 1 completely. The signal will be level translated to a V_{CC2} logic level and available on Y2, where it may be applied directly to the input of Device 2. In bypass mode, Y1 is pulled up to V_{CC1} .

The three supplies in Figure 35 and Figure 36 may be any combination of supplies, that is., V_{CC0} , V_{CC1} , and V_{CC2} may be any combination of supplies, for example, 1.8 V, 2.5 V, and 3.3 V.

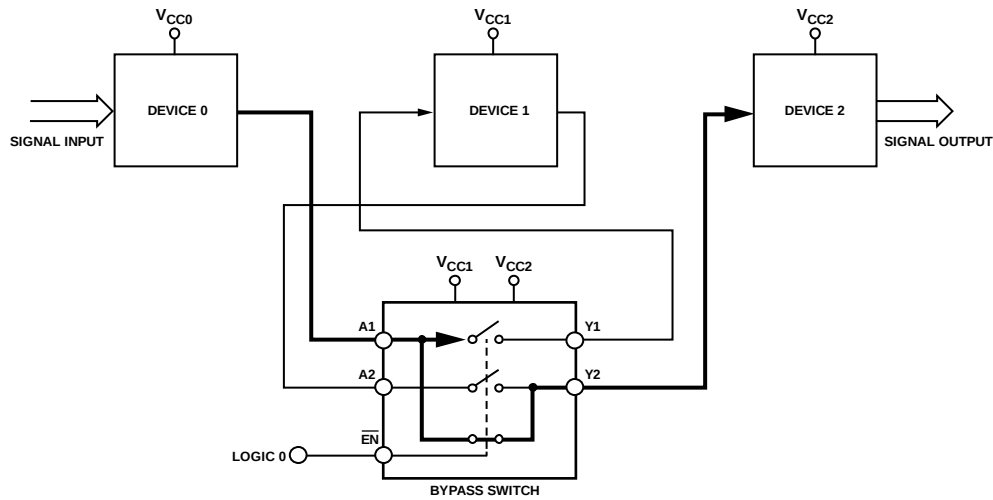
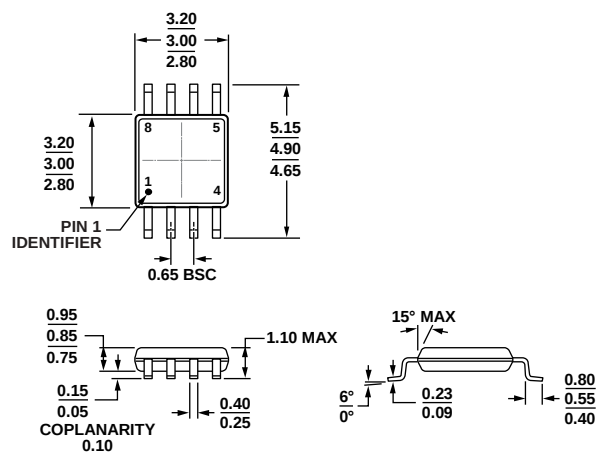


Figure 36. Bypass Switch in Bypass Mode

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OUTLINE DIMENSIONS

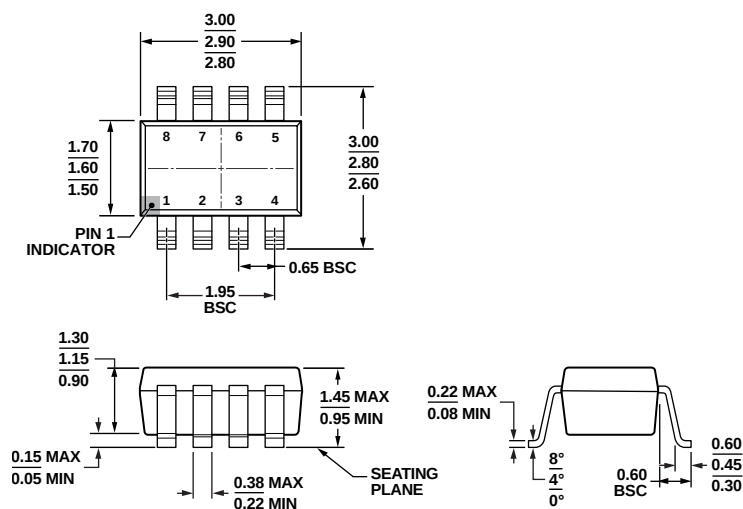


COMPLIANT TO JEDEC STANDARDS MO-187-AA

Figure 37. 8-Lead Mini Small Outline Package [MSOP]
(RM-8)

Dimensions shown in millimeters

10-07-2009-B



COMPLIANT TO JEDEC STANDARDS MO-178-BA

Figure 38. 8-Lead Small Outline Transistor Package [SOT-23]
(RJ-8)

Dimensions shown in millimeters

12-16-2008-A

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Branding	Package Option
ADG3233BRJ-REEL7	–40°C to +85°C	8-Lead SOT-23	W1B	RJ-8
ADG3233BRJZ-REEL7	–40°C to +85°C	8-Lead SOT-23	S1S	RJ-8
ADG3233BRMZ	–40°C to +85°C	8-Lead MSOP	S1S	RM-8

¹ Z = RoHS Compliant Part.

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